Silicon P Channel MOS FET High Speed Power Switching

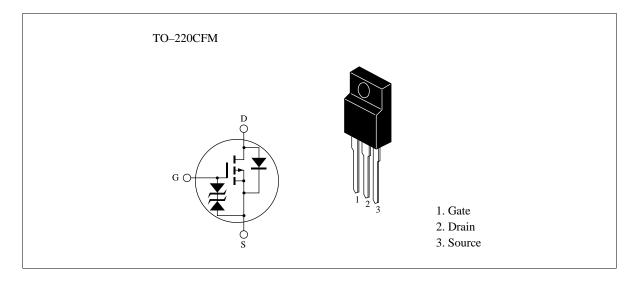
HITACHI

ADE-208-638A (Z) 2nd. Edition Jul. 1998

Features

- Low on-resistance $R_{DS(on)} = 0.075\Omega$ typ.
- Low drive current.
- 4V gate drive devices.
- High speed switching.

Outline





Absolute Maximum Ratings (Ta = 25°C)

V _{DSS}	-60	V	
		•	
V _{GSS}	±20	V	
I _D	-15	А	
Note1	-60	А	
it I _{DR}	-15	А	
AP Note3	-15	А	
E _{AR} ^{Note3}	19	mJ	
Pch Note2	30	W	
Tch	150	°C	
Tstg	-55 to +150	°C	
	$ \frac{I_{D(pulse)}^{Note1}}{I_{DR}} $ $ \frac{I_{AP}^{Note3}}{E_{AR}^{Note3}} $ $ \frac{Pch^{Note2}}{Tch} $	$\begin{array}{c c} I_{D} & -15 \\ \hline I_{D(pulse)}^{Note1} & -60 \\ \hline nt & I_{DR} & -15 \\ \hline I_{AP}^{Note3} & -15 \\ \hline E_{AR}^{Note3} & 19 \\ \hline Pch^{Note2} & 30 \\ \hline Tch & 150 \\ \end{array}$	Image: register of the second system Image: register of the second system Image: register of the second system I I D(pulse) -15 A I I D(pulse) 0 MI I D(pulse) 0 MI MI I D(pulse) 0 WI MI I D(pulse) 0 WI MI I D(pulse) 0 C MI

Note: 1. $PW \le 10\mu s$, duty cycle $\le 1 \%$

2. Value at Tc = $25^{\circ}C$

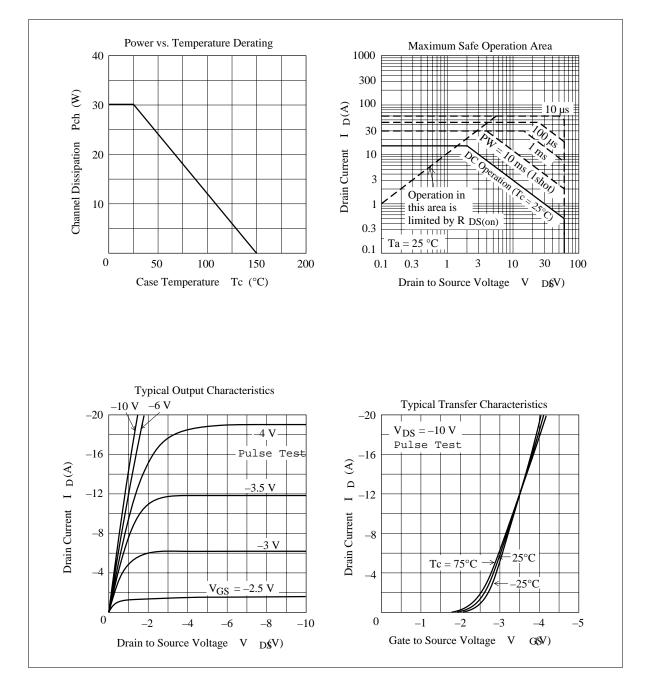
3. Value at Tch = 25°C, Rg \geq 50 Ω

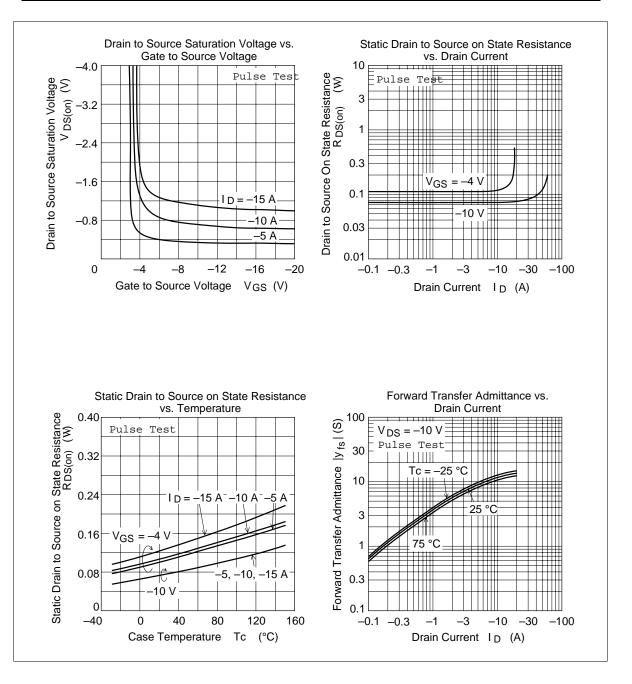
Electrical Characteristics (Ta = 25° C)

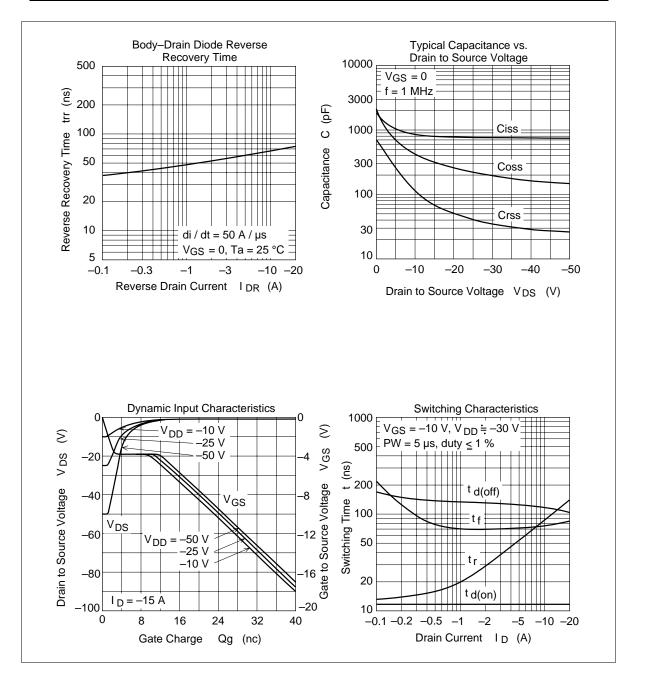
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	-60	_	_	V	$I_{\rm D} = -10$ mA, $V_{\rm GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_	_	V	$I_{g} = \pm 100 \mu A, V_{DS} = 0$
Zero gate voltege drain current	I _{DSS}	—	_	-10	μA	$V_{\rm DS} = -60 \text{ V}, \text{ V}_{\rm GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±10	μA	$V_{GS} = \pm 16V, V_{DS} = 0$
Gate to source cutoff voltage	$V_{\text{GS(off)}}$	-1.0	_	-2.0	V	$I_{\rm D} = -1$ mA, $V_{\rm DS} = -10$ V
Static drain to source on state	$R_{DS(on)}$	_	0.075	0.095	Ω	$I_{\rm D} = -8A, V_{\rm GS} = -10V^{\rm Note4}$
resistance	$R_{DS(on)}$	_	0.105	0.155	Ω	$I_{\rm D} = -8A, V_{\rm GS} = -4V^{\rm Note4}$
Forward transfer admittance	y _{fs}	6.5	11	_	S	$I_{\rm D} = -8A, V_{\rm DS} = 10V^{\rm Note4}$
Input capacitance	Ciss	_	850	_	pF	$V_{\rm DS} = -10V$
Output capacitance	Coss	_	420	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	110	_	pF	f = 1MHz
Turn-on delay time	t _{d(on)}	—	12	_	ns	$V_{GS} = -10V, I_{D} = -8A$
Rise time	t,	_	75	_	ns	$R_{L} = 3.75\Omega$
Turn-off delay time	t _{d(off)}	_	125	_	ns	_
Fall time	t _f	_	75	_	ns	_
Body-drain diode forward voltage	V _{DF}	_	-1.1	_	V	$I_{F} = -15A, V_{GS} = 0$
Body–drain diode reverse recovery time	t _{rr}	_	70	_	ns	I _F = -15A, V _{GS} = 0 diF/ dt =50A/μs

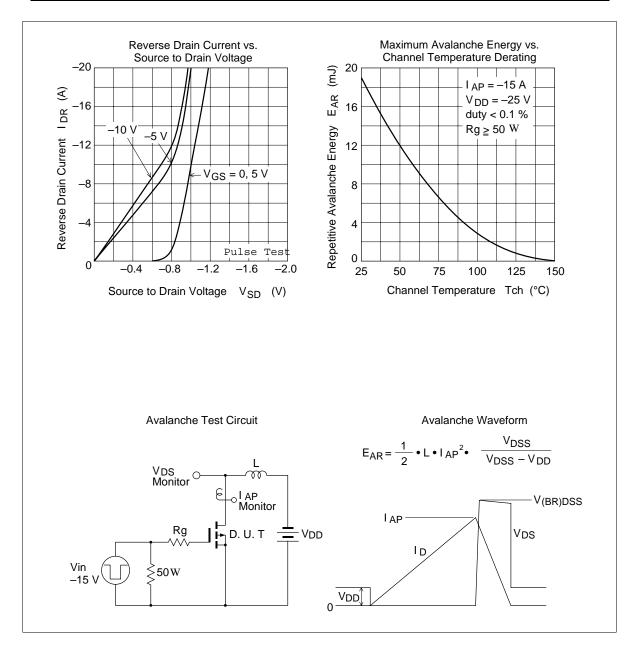
Note: 4. Pulse test

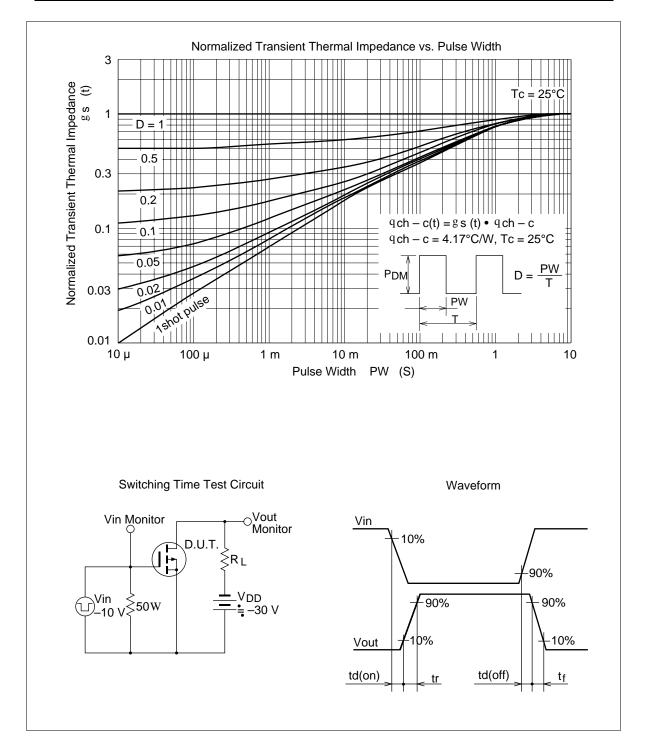
Main Characteristics



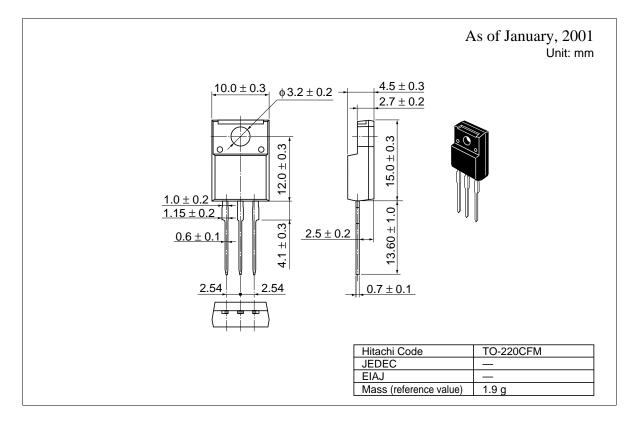








Package Dimensions



Cautions

- 1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
- 2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
- 3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
- 4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as failsafes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
- 5. This product is not designed to be radiation resistant.
- 6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
- 7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

ITACH

Hitachi, Ltd.

Semiconductor & Integrated Circuits. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL	NorthAmerica Europe		http://semiconductor.hitachi.com/ http://www.hitachi-eu.com/hel/ecg
	Asia Japan	:	http://sicapac.hitachi-asia.com http://www.hitachi.co.jp/Sicd/indx.htm

For further information write to:

Hitachi Semiconductor
(America) Inc.
179 East Tasman Drive,
San Jose,CA 95134
Tel: <1> (408) 433-1990
Fax: <1>(408) 433-0223

Hitachi Europe GmbH Electronic Components Group Dornacher Straße 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd.

Electronic Components Group. Whitebrook Park Lower Cookham Road Maidenhead Berkshire SL6 8YA, United Kingdom Tel : <886>-(2)-2718-3666 Tel: <44> (1628) 585000 Fax: <44> (1628) 585160

Hitachi Asia Ltd. Hitachi Tower 16 Collyer Quay #20-00, Singapore 049318 Tel : <65>-538-6533/538-8577 Fax : <65>-538-6933/538-3877 URL : http://www.hitachi.com.sg

Hitachi Asia Ltd (Taipei Branch Office) 4/F, No. 167, Tun Hwa North Road, Hung-Kuo Building. Taipei (105), Taiwan Fax : <886>-(2)-2718-8180 Telex : 23222 HAS-TP URL : http://www.hitachi.com.tw

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852>-(2)-735-9218 Fax : <852>-(2)-730-0281 URL : http://www.hitachi.com.hk

Copyright © Hitachi, Ltd., 2000. All rights reserved. Printed in Japan. Colophon 2.0